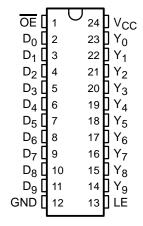
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- **Function, Pinout, and Drive Compatible** With FCT, F, and AM29841 Logic
- Reduced V_{OH} (Typically = 3.3 V) Versions of **Equivalent FCT Functions**
- **Edge-Rate Control Circuitry for Significantly Improved Noise** Characteristics
- Ioff Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- **Fully Compatible With TTL Input and Output Logic Levels**
- **High-Speed Parallel Latches**
- **Buffered Common Latch-Enable Input**
- **3-State Outputs**
- CY54FCT841T
 - 32-mA Output Sink Current
 - 12-mA Output Source Current
- CY74FCT841T
 - 64-mA Output Sink Current
 - 32-mA Output Source Current

CY54FCT841T . . . D PACKAGE CY74FCT841T . . . P. Q. OR SO PACKAGE (TOP VIEW)



description

The 'FCT841T bus-interface latches are designed to eliminate additional packages required to buffer existing latches and provide additional data width for wider address/data paths or buses carrying parity. The 'FCT841T devices are buffered 10-bit-wide versions of the FCT373 function.

The 'FCT841T devices' high-performance interface is designed for high-capacitance-load drive capability, while providing low-capacitance bus loading at both inputs and outputs. Outputs are designed for low-capacitance bus loading in the high-impedance state.

These devices are fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

PIN DESCRIPTION

NAME	I/O	DESCRIPTION
D	I	Latch data inputs
LE	ı	Latch-enable input. The latches are transparent when LE is high. Input data is latched on the high-to-low transition.
Υ	0	3-state latch outputs
ŌĒ	ı	Output-enable control. When OE is low, the outputs are enabled. When OE is high, the outputs are in the high-impedance (off) state.



testing of all parameters.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of



ORDERING INFORMATION

TA	PACI	(AGE [†]	SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QSOP - Q	Tape and reel	5.5	CY74FCT841CTQCT	FCT841C
	SOIC - SO	Tube	5.5	CY74FCT841CTSOC	FCT841C
–40°C to 85°C	3010 - 30	Tape and reel	5.5	CY74FCT841CTSOCT	FC1041C
-40 C to 65 C	DIP – P	Tube	6.5	CY74FCT841BTPC	CY74FCT841BTPC
	SOIC - SO	Tube	9	CY74FCT841ATSOC	FCT841A
	3010 - 30	Tape and reel	9	CY74FCT841ATSOCT	FC1041A
–55°C to 125°C	CDIP – D	Tube	10	CY54FCT841ATDMB	

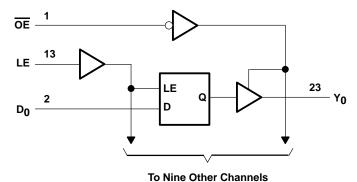
[†]Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

IN	INPUTS		INTER OUT	RNAL PUTS	FUNCTION
Ē	LE	D	0	Υ	
1	Х	Х	Х	Z	
ł	Н	L	L	Z	Z
1	Н	Н	Н	Z	
ł	L	Χ	NC	Z	Latched (Z)
-	Н	L	L	L	Transparent
-	Н	Н	Н	Н	Transparent
-	L	Х	NC	NC	Latched

H = High logic level, L = Low logic level, X = Don't care, NC = No change, Z = High-impedance state

logic diagram (positive logic)



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range to ground potential	-0.5	V to 7 V
DC input voltage range	-0.5	V to 7 V
DC output voltage range	-0.5	V to $7\ V$
DC output current (maximum sink current/pin)		120 mA
Package thermal impedance, θ _{JA} (see Note 1): P package		67°C/W
(see Note 2): Q package		61°C/W
(see Note 2): SO package		46°C/W
Ambient temperature range with power applied, T _A –	65°C t	o 135°C
Storage temperature range, T _{stq} –	65°C t	o 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 3)

		CY54FCT841T			CY7	74FCT84	1T	UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNII
VCC	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.8			0.8	V
ІОН	High-level output current			-12			-32	mA
loL	Low-level output current			32			64	mA
TA	Operating free-air temperature	-55		125	-40		85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.



NOTES: 1. The package thermal impedance is calculated in accordance with JESD 51-3.

^{2.} The package thermal impedance is calculated in accordance with JESD 51-7.

CY54FCT841T, CY74FCT841T 10-BIT LATCHES WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETER		TEST CONDITION	NG.	CY	54FCT84	I1T	CY	74FCT84	1T	LINUT			
PARAMETER		TEST CONDITION	NS	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNIT			
Viva	$V_{CC} = 4.5 \text{ V},$	$I_{IN} = -18 \text{ mA}$			-0.7	-1.2				٧			
VIK	$V_{CC} = 4.75 \text{ V},$	I _{IN} = -18 mA						-0.7	-1.2	V			
	V _{CC} = 4.5 V,	I _{OH} = -12 mA		2.4	3.3								
Voн	V 475 V	I _{OH} = -32 mA					2			V			
	V _{CC} = 4.75 V	I _{OH} = -15 mA					2.4	3.3					
	V _{CC} = 4.5 V,	I _{OL} = 32 mA			0.3	0.55							
VOL	V _{CC} = 4.75 V,	I _{OL} = 64 mA						0.3	0.55	V			
V _{hys}	All inputs				0.2			0.2		V			
	$V_{CC} = 5.5 \text{ V},$	V _{IN} = V _{CC}				5							
l 1	V _{CC} = 5.25 V,	VIN = VCC							5	μΑ			
lін	$V_{CC} = 5.5 \text{ V},$	V _{IN} = 2.7 V				±1							
	V _{CC} = 5.25 V,	V _{IN} = 2.7 V							±1	μΑ			
	$V_{CC} = 5.5 \text{ V},$	V _{IN} = 0.5 V				±1							
l⊓l⊓	V _{CC} = 5.25 V,	V _{IN} = 0.5 V							±1	μΑ			
	$V_{CC} = 5.5 \text{ V},$	V _{OUT} = 2.7 V			-	10							
lozh	$V_{CC} = 5.25 \text{ V},$	V _{OUT} = 2.7 V						-	10	μΑ			
	V _{CC} = 5.5 V,	V _{OUT} = 0.5 V				-10				+			
lozL	V _{CC} = 5.25 V,	V _{OUT} = 0.5 V							-10	μΑ			
. +	$V_{CC} = 5.5 \text{ V},$	V _{OUT} = 0 V		-60	-120	-225				^			
los [‡]	V _{CC} = 5.25 V,	V _{OUT} = 0 V					-60	-120	-225	mA			
l _{off}	$V_{CC} = 0 V$	V _{OUT} = 4.5 V				±1			±1	μΑ			
	$V_{CC} = 5.5 \text{ V},$	V _{IN} ≤ 0.2 V,	V _{IN} ≥ V _{CC} - 0.2 V		0.1	0.2				4			
Icc	V _{CC} = 5.25 V,	$V_{IN} \le 0.2 V$,	$V_{IN} \ge V_{CC} - 0.2 \text{ V}$					0.1	0.2	mA			
Aloo	$V_{CC} = 5.5 \text{ V}, V_{IN} =$	= 3.4 V [§] , f ₁ = 0, Ou	tputs open		0.5	2				mA			
ΔICC	$V_{CC} = 5.25 \text{ V}, V_{IN}$	$= 3.4 \text{ V}$, $f_1 = 0$, O	utputs open					0.5	2	IIIA			
	V _{CC} = 5.5 V, One i		0% duty cycle,		0.06	0.12							
, ,	$V_{IN} \le 0.2 \text{ V or } V_{IN}$				0.00	0.12				mA/			
ICCD [¶]	V _{CC} = 5.25 V, <u>One</u>	input switching at	50% duty cycle,		•			-		MHz			
	Outputs open, OE : V _{IN} ≤ 0.2 V or V _{IN}					0.06	0.12						
± ==	VIN S 0.2 V 01 VIN												

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



[‡] Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, IOS tests should be performed last.

 $[\]S$ Per TTL-driven input (V_{IN} = 3.4 V); all other inputs at V_{CC} or GND

This parameter is derived for use in total power-supply calculations.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)

DADAMETER		TEST CONDITION	ie.	CY	54FCT84	11T	CY	74FCT84	1T	LINIT
PARAMETER		TEST CONDITION		MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNIT
	V _{CC} = 5.5 V,	One bit switching at f ₁ = 10 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.7	1.4				
	Outputs open,	at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		1	2.4				
OE = GND, LE = VCC	10 bits switching at f ₁ = 2.5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		1	3.2					
		at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		4.1	13.2				mA
ıC"	V _{CC} = 5.25 V,	One bit switching at f ₁ = 10 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$					0.7	1.4	IIIA
	Outputs open,	at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$					1	2.4	
	OE = GND, LE = V _{CC}	10 bits switching at f ₁ = 2.5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$					1	3.2	
		at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$					4.1	13.2	
C _i					5	10		5	10	pF
Co		•			9	12		9	12	pF

† Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$. # $I_{CC} = I_{CC} + \Delta I_{CC} \times D_H \times N_T + I_{CCD} (f_0/2 + f_1 \times N_1)$

Where:

= Total supply current IC

I_{CC} = Power-supply current with CMOS input levels

 ΔI_{CC} = Power-supply current for a TTL high input ($V_{IN} = 3.4 \text{ V}$)

D_H = Duty cycle for TTL inputs high N_T = Number of TTL inputs at D_H

ICCD = Dynamic current caused by an input transition pair (HLH or LHL)

= Clock frequency for registered devices, otherwise zero

= Input signal frequency

= Number of inputs changing at f₁

All currents are in milliamperes and all frequencies are in megahertz.

|| Values for these conditions are examples of the I_{CC} formula.

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

		CY54FCT841AT		CY74FCT841AT		CY74FCT841BT		CY74FCT841CT		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _W	Pulse duration, LE high	5		4		4		4		ns
t _{su}	Setup time, data before LE↑	2.5		2.5		2.5		2.5		ns
th	Hold time, data after LE↑	3		2.5		2.5		2.5		ns



CY54FCT841T, CY74FCT841T 10-BIT LATCHES WITH 3-STATE OUTPUTS

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switching characteristics over operating free-air temperature range (see Figure 1)

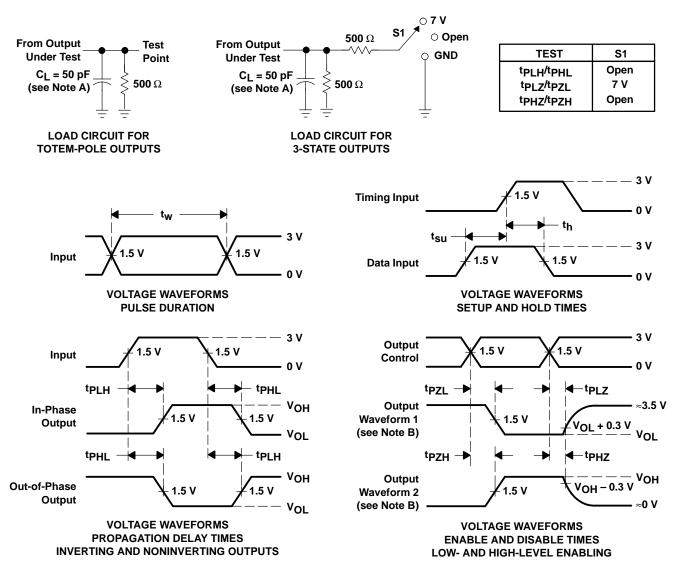
DARAMETER	FROM	то	TEST LOAD	CY54FCT	841AT	CY74FCT	841AT	UNIT
PARAMETER	(INPUT)	(OUTPUT)	TEST LOAD	MIN	MAX	MIN	MAX	UNII
t _{PLH}	D	Υ	C _L = 50 pF,	1.5	10	1.5	9	ns
^t PHL	D	I	$R_L = 500 \Omega$	1.5	10	1.5	9	115
^t PLH	כ	D Y $C_L = 300 \text{ pF}, \\ R_L = 500 \Omega$	C _L = 300 pF,	1.5	15	1.5	13	ns
^t PHL	D		1.5	15	1.5	13	115	
^t PLH	LE	Y	C _L = 50 pF,	1.5	13	1.5	12	20
^t PHL	LE	I	$R_L = 500 \Omega$	1.5	13	1.5	12	ns
^t PLH	LE	LE Y	C _L = 300 pF,	1.5	20	1.5	16	ns
^t PHL	LL	I	$R_L = 500 \Omega$	1.5	20	1.5	16	113
^t PZH	<u>OE</u>	Y	C _L = 50 pF,	1.5	13	1.5	11.5	ns
^t PZL	OE	$R_L = 500 \Omega$		1.5	13	1.5	11.5	115
^t PZH	ŌĒ	Y	C _L = 300 pF,	1.5	25	1.5	23	20
^t PZL	OE	I	$R_L = 500 \Omega$	1.5	25	1.5	23	ns
^t PHZ	ŌĒ	Y	C _L = 5 pF,	1.5	9	1.5	7	ns
^t PLZ	OE	Y	$R_L = 500 \Omega$	1.5	9	1.5	7	115
^t PHZ	-	Υ	C _L = 50 pF,	1.5	10	1.5	8	ns
^t PLZ	OE	OE Y		1.5	10	1.5	8	119

switching characteristics over operating free-air temperature range (see Figure 1)

DADAMETED	FROM	то	TEST LOAD	CY74FCT	841BT	CY74FCT	841CT	LINIT
PARAMETER	(INPUT)	(OUTPUT)	TEST LOAD	MIN	MAX	MIN	MAX	UNIT
^t PLH	D	Y	C _L = 50 pF,	1.5	6.5	1.5	5.5	
^t PHL]	ī	$R_L = 500 \Omega$	1.5	6.5	1.5	5.5	ns
^t PLH	D	Y	C _L = 50 pF,	1.5	13	1.5	13	ns
^t PHL]	1	$R_L = 500 \Omega$	1.5	13	1.5	13	115
^t PLH	LE	Y	C _L = 50 pF,	1.5	8	1.5	6.4	no
^t PHL] "	ī	$R_L = 500 \Omega$	1.5	8	1.5	6.4	ns
^t PLH	LE	Y	$C_L = 300 \text{ pF},$	1.5	15.5	1.5		no
^t PHL		ī	$R_L = 500 \Omega$	1.5	15.5	1.5	15	ns
^t PZH	OE	Y C _I	C _L = 50 pF,	1.5	8	1.5	6.5	ns
t _{PZL}] OE	Ť	$R_L = 500 \Omega$	1.5	8	1.5	6.5	ns
^t PZH	OE	Y	C _L = 300 pF,	1.5	14	1.5	12	
t _{PZL}	OE OE	Ť	$R_L = 500 \Omega$	1.5	14	1.5	12	ns
^t PHZ		Y	C _L = 5 pF,	1.5	6	1.5	5.7	no
^t PLZ	ŌĒ	T T	$R_L = 500 \Omega$	1.5	6	1.5	5.7	ns
^t PHZ		Y	C _L = 50 pF	1.5	7	1.5	6	no
t _{PLZ}	OE	Ĭ Ť	$R_L = 500 \Omega$,	1.5	7	1.5	6	ns



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

PACKAGE OPTION ADDENDUM

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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
5962-88575013A	ACTIVE	LCCC	FK	28	1	TBD	POST-PLATE	N / A for Pkg Type
CY54FCT841ATDMB	ACTIVE	CDIP	JT	24	1	TBD	A42	N / A for Pkg Type
CY54FCT841ATLMB	ACTIVE	LCCC	FK	28	1	TBD	POST-PLATE	N / A for Pkg Type
CY74FCT841ATSOC	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT841ATSOCE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT841ATSOCG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT841ATSOCT	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT841ATSOCTE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT841ATSOCTG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT841BTPC	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CY74FCT841BTPCE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CY74FCT841CTQCT	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT841CTQCTE4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT841CTQCTG4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT841CTSOC	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT841CTSOCE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT841CTSOCG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT841CTSOCT	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT841CTSOCTE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT841CTSOCTG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Tl's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

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at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

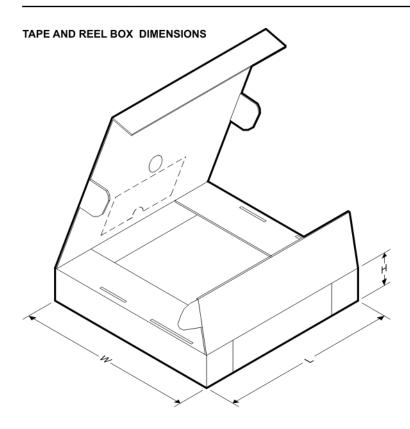
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT841ATSOCT	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CY74FCT841CTQCT	SSOP/ QSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT841CTSOCT	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1





*All dimensions are nominal

7 III GITTIOTIOTOTIC GITC TIGITIITIGI								
Device	Package Type	Package Drawing	Pins SPQ		Length (mm)	Width (mm)	Height (mm)	
CY74FCT841ATSOCT	SOIC	DW	24	2000	346.0	346.0	41.0	
CY74FCT841CTQCT	SSOP/QSOP	DBQ	24	2500	346.0	346.0	33.0	
CY74FCT841CTSOCT	SOIC	DW	24	2000	346.0	346.0	41.0	

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